



P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
	0.0073 at V _{GS} = - 4.5 V	- 20			
- 20	0.0090 at V _{GS} = - 2.5 V	- 18			
	0.013 at V _{GS} = - 1.8 V	- 15			

FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFETs
- New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile

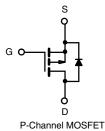


FREE

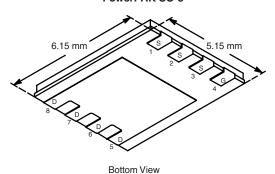
APPLICATIONS

· Battery Switch for Portable Devices





PowerPAK SO-8



Ordering Information: Si7485DP-T1-E3 (Lead (Pb)-free)

Si7485DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 20		V
Gate-Source Voltage	V _{GS}	± 8		V	
Continuous Prain Current (T. – 150 °C)a	T _A = 25 °C	I _D	- 20	- 12.5	А
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 16.5	- 9.5	
Pulsed Drain Current		I _{DM}	- 50		А
Continuous Source Current (Diode Conduction) ^a	I _S	- 4.5	- 1.6		
Maximum Dawar Discipations	T _A = 25 °C	P _D	5	1.8	W
Maximum Power Dissipation ^a	T _A = 70 °C		3.2	1.1	"
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b,c}			2	260	C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Marrian de Ambienta	t ≤ 10 s	R _{thJA}	20	25		
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	54	68	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.7	2.2]	

Notes

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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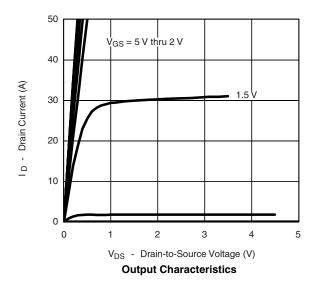
SPECIFICATIONS $T_J = 25$	°C, unless	otherwise noted					
Parameter	Symbol	Test Condition	Тур.	Max.	Unit		
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -1$ mA	- 0.4		- 0.9	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zana Oata Wallana Busin Oamant		V _{DS} = - 20 V, V _{GS} = 0 V	20 40			μΑ	
Zero Gate Voltage Drain Current	IDSS	V_{DS} = - 20 V, V_{GS} = 0 V, T_{J} = 70 °C					
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge -5 V$, $V_{GS} = -4.5 V$	- 40			Α	
		V _{GS} = - 4.5 V, I _D = - 20 A		0.006	0.0073		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 18 A		0.0074	0.0090	Ω	
	-(-,	V _{GS} = - 1.8 V, I _D = - 15 A		0.0106	0.013		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 20 A		80		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 4.5 A, V _{GS} = 0 V		- 0.62	- 1.1	V	
Dynamic ^b			•	•			
Total Gate Charge	Q_g			99	150		
Gate-Source Charge	Q _{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -5 \text{ V}, I_{D} = -20 \text{ A}$		11.5		nC	
Gate-Drain Charge	Q _{gd}			29			
Gate Resistance	R_{g}			2.4		Ω	
Turn-On Delay Time	t _{d(on)}			80	120		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		140	210	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -1$ A, $V_{GEN} = -4.5$ V, $R_g = 6 \Omega$		360	540		
Fall Time	t _f			170	260		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -2.9 \text{ A, dI/dt} = 100 \text{ A/}\mu\text{s}$		55	80		

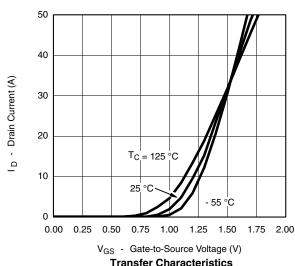
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Transfer Characteristics

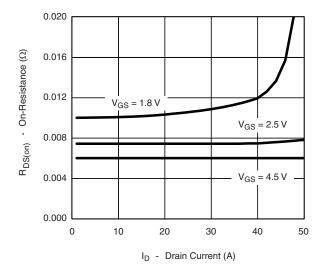




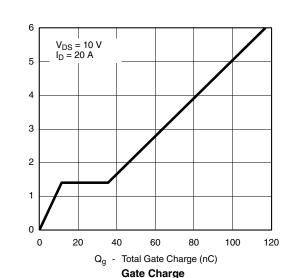


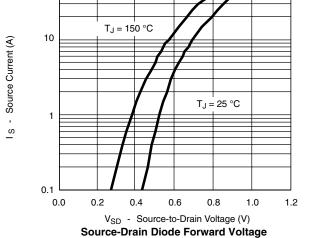
V_{GS} - Gate-to-Source Voltage (V)

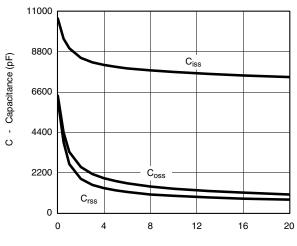
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current

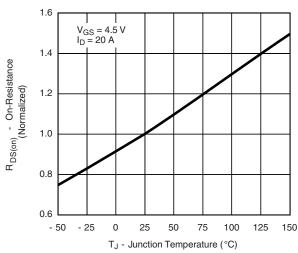




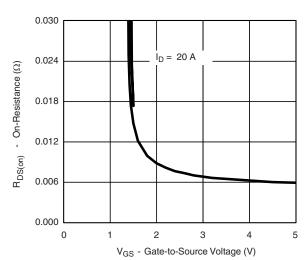


V_{DS} - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature



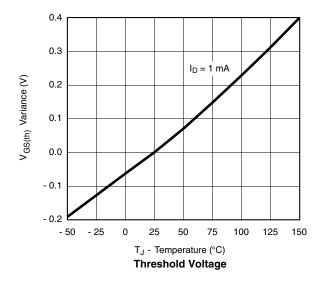
On-Resistance vs. Gate-to-Source Voltage

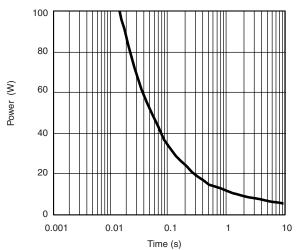
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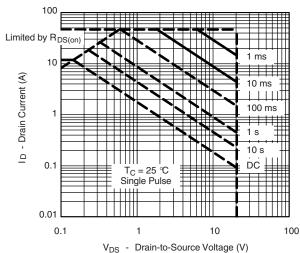
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

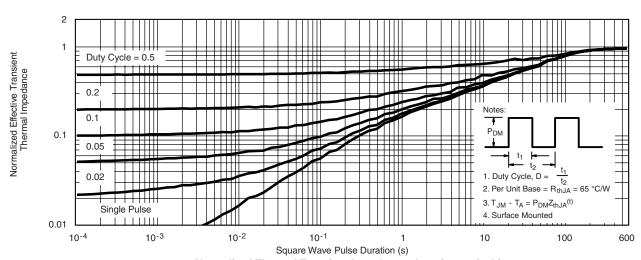




Single Pulse Power, Junction-to-Ambient



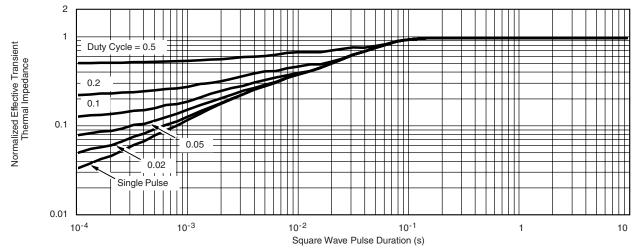
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72275.



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



	3. Dimensions exclusive	of mold flash and cuttin	g burrs.					
DIM.		MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
A	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
	4.00	4.00	F 00	0.400	0.400	0.407		

Α	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.56	3.76	3.91	0.140	0.148	0.154	
D3	1.32	1.50	1.68	0.052	0.059	0.066	
D4		0.57 typ.			0.0225 typ.		
D5		3.98 typ.			0.157 typ.		
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	5.79	5.89	5.99	0.228	0.232	0.236	
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144	
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151	
E3	3.68	3.78	3.91	0.145	0.149	0.154	
E4 (for AL product)		0.58 typ.		0.023 typ.			
E4 (for other product)		0.75 typ.		0.030 typ.			
е		1.27 BSC		0.050 BSC			
K (for AL product)		1.45 typ.		0.057 typ.			
K (for other product)		1.27 typ.		0.050 typ.			
K1	0.56	-	=	0.022	-	=	
Н	0.51	0.61	0.71	0.020	0.024	0.028	
L	0.51	0.61	0.71	0.020	0.024	0.028	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
M	0.125 typ.			0.005 typ.			
ECN: C13-0702-Rev. K, 20)-May-13			•			

Revison: 20-May-13 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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